NSN 5962-01-047-2035

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view Online at https://aerobasegroup.com/nsn/5962-01-047-2035
Body Length:
Between 1.200 inches and 1.300 inches
Body Width:
Between 0.500 inches and 0.600 inches
Body Height:
0.320 inches
Maximum Power Dissipation Rating:
1.5 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and negative outputs and positive outputs and high speed and 3-state output and programmable and
w/decoded output and w/buffered output
Inclosure Material:
Ceramic and metal
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
15.0 volts power source
Time Rating Per Chacteristic:
20.00 nanoseconds propagation delay time, low to high level output and 20.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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